

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	-20	V
Gate-Source Voltage			Vgss	-12	V
Continuous Drain Current (Note 5) V _{GS} = -8V	Steady State	T _A = +25°C T _A = +70°C	ID	-3.4 -2.7	A
Continuous Drain Current (Note 5) V_{GS} = -4.5V	Steady State	T _A = +25°C T _A = +70°C	ID	-3.0 -2.4	А
Pulsed Drain Current (Note 6)			Ідм	-13	А
Human Body Model (HBM)			V _(ESD)	4	kV

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	0.81	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 7)	R _{0JA}	155.4	°C/W
Power Dissipation (Note 5)	PD	1.4	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R _{0JA}	90.4	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BVDSS	-20	—	—	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current TJ = +25°C	IDSS	_	—	-100	nA	V _{DS} = -16V, V _{GS} = 0V	
Gate-Source Leakage	lgss	_	—	-50	nA	V _{GS} = -12V, V _{DS} = 0V	
ON CHARACTERISTICS (Note 8)	•		•	•	•	·	
Gate Threshold Voltage	V _{GS(TH)}	-0.7	-0.9	-1.2	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance		—	64	78	·mΩ	VGS = -8V, ID = -0.5A	
	Descen	—	77	100		VGS = -4.5V, ID = -0.5A	
	Rds(on)	_	113	165		$V_{GS} = -2.5V, I_D = -0.5A$	
		_	188	600		$V_{GS} = -1.8V, I_D = -0.1A$	
Diode Forward Voltage	Vsd		-0.7	-1.0	V	VGS = 0V, IS = -0.5A	
Reverse Recovery Charge	Qrr		1.3	—	nC	V _{DD} = -10V, I _F = -1A,	
Reverse Recovery Time	t _{RR}	_	7.7	—	ns	di/dt = 100A/µs	
DYNAMIC CHARACTERISTICS (Note 9)						-	
Input Capacitance	Ciss	—	152	228		$V_{DS} = -10V, V_{GS} = 0V,$ f = 1MHz	
Output Capacitance	Coss	_	78	117	pF		
Reverse Transfer Capacitance	Crss	_	4.3	6.4			
Series Gate Resistance	R _G	_	21	31	Ω	$f = 1MHz$, $V_{GS} = 0V$, $V_{DS} = 0V$	
Total Gate Charge	Qg	_	1.1	1.6			
Gate-Source Charge	Qgs		0.2	_	nC	$V_{GS} = -4.5V, V_{DS} = -10V,$ $I_{D} = -0.5A$	
Gate-Drain Charge	Q _{gd}		0.2	_	nC		
Gate Charge at VTH	Qg(th)		3.6	_			
Turn-On Delay Time	tD(ON)	_	4.1	6.1		$V_{DS} = -10V, V_{GS} = -4.5V,$ $R_G = 2\Omega, I_D = -0.5A$	
Turn-On Rise Time	tR	_	5.6	—	1		
Turn-Off Delay Time	t _{D(OFF)}	_	9.5	14.2	ns		
Turn-Off Fall Time	tF		4.6	_	1		

5. Device mounted on FR-4 material with 1inch² (6.45cm²), 2oz. (0.071mm thick) Cu.

6. Repetitive rating, pulse width limited by junction temperature.

7. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.

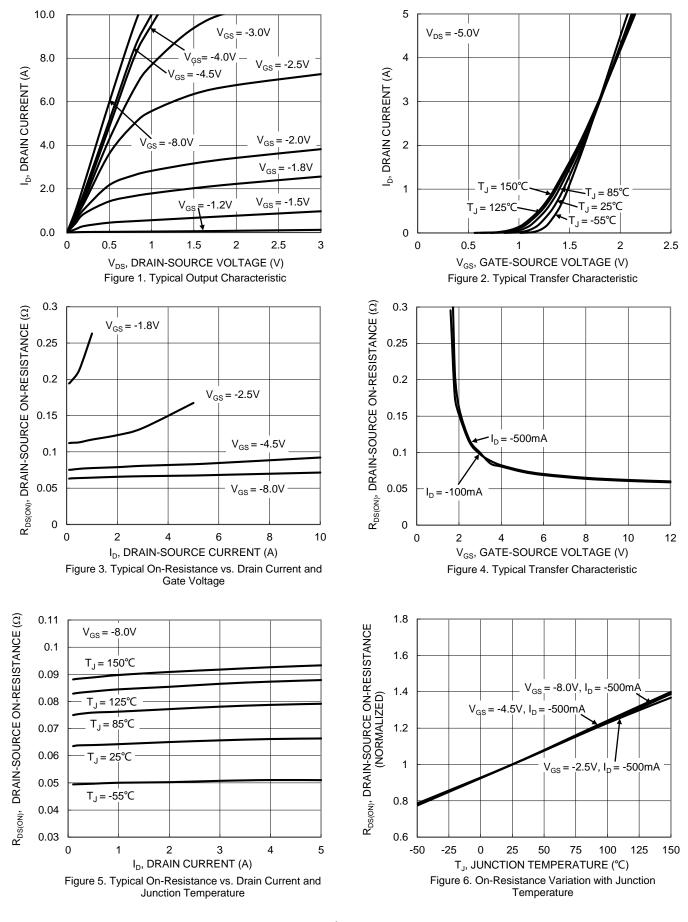
8. Short duration pulse test used to minimize self-heating effect.

9. Guaranteed by design. Not subject to production testing.

Notes:



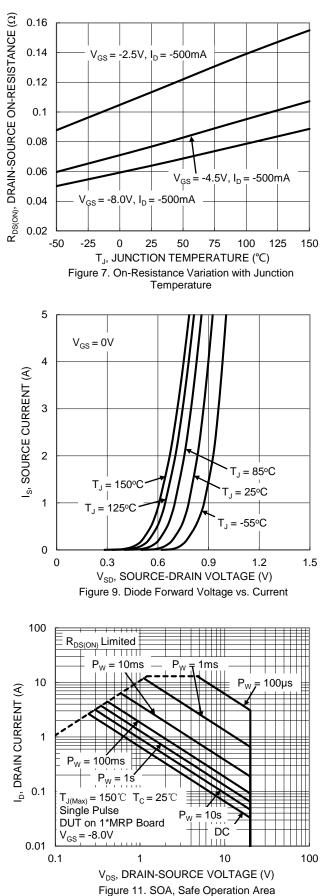
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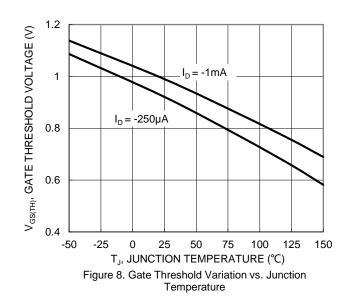


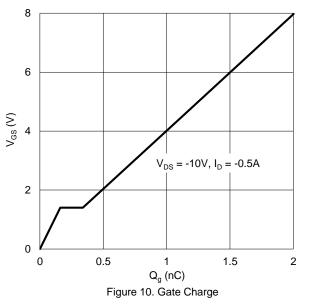
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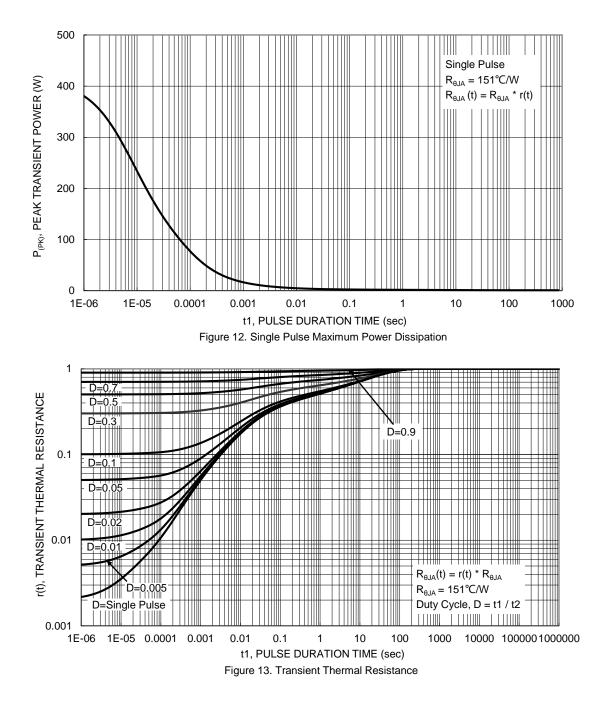
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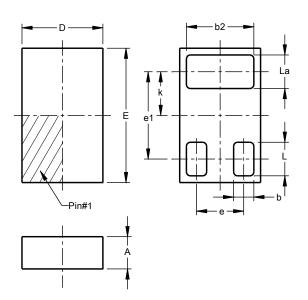




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

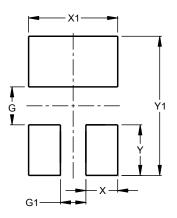




	X4-DSN1006-3					
Dim	Min	Max	Тур			
Α	0.18	0.22	0.20			
b	0.14	0.16	0.15			
b2	0.49	0.51	0.50			
D	0.56	0.64	0.60			
E	0.96	1.04	1.00			
е			0.35			
e1			0.65			
k			0.325			
L	0.24	0.26	0.25			
La	0.24	0.26	0.25			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



X4-DSN1006-3

Dimensions	Value (in mm)
G	0.40
G1	0.20
Х	0.15
X1	0.50
Y	0.25
Y1	0.90



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